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P. S. Rao

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION of

Jun Kanamori

Serial No.: 09/398,189

Filed: September 17, 1999

Claims changed

Group Art Unit: 2814

Examiner: S. Rao

For: METHOD OF FABRICATING A SEMICONDUCTOR DEVICE WITH SELF-
ALIGNED SILICIDE AREAS FORMED USING A SUPPLEMENTAL SILICON
OVERLAYER

*Bel
1223-02*

AMENDMENT UNDER 37 C.F.R. §1.116

Honorable Assistant Commissioner for Patents
Washington, D.C. 20231

Date: July 23, 2002

Sir:

In response to the Final Office Action dated April 29, 2002, the following
amendments and remarks are respectfully submitted in connection with the above-
identified application.

In the Claims:

Please cancel claim 23 without prejudice or disclaimer of the subject matter
contained therein.

The following replacement claims are respectfully submitted:

2. (Three times Amended) The method according to claim 30, wherein the metal
layer comprises cobalt.

EI 5/1